talliz d and t xtured using a r petitive sequenc incremental reaction and m chanical swaging steps. During the formation f metal-ceramic composites that comprise a ceramic member possessing a thermal reaction temperature in excess of the melting temperature of the metal member to which it is bonded, it is preferred to utilize electromagnetic radiation to react and crystallize the ceramic member. In this embodiment a beam of electromagnetic radiation, characterized by an electromagnetic energy that is either in the microwave frequency spectrum or in the infrared frequency spectrum, can be directed onto the ceramic member to advance its state of crystallization. Simultaneously, the metal member, which is not irradiated by a suitably directed electromagnetic beam, can be held to a temperature well below its melting point. It is now well known to practitioners skilled in the art of microwave

annealing of ceramic and other materials, that certain

frequencie

cting, or magneto-sensitive pr perties.

An optional step "F" is used in which the amorphous oxide coating 17 of article 15 is thermally reacted, or reacted by exposure to electromagnetic radiation at frequencies in the microwave or optical spectrum, in a controlled gas atmosphere to form an article 19 that comprises a fully or partially crystallized randomly oriented ceramic layer 21 on a substrate 9. Any such processing treatment that advances the state of crystallinity in the ceramic layer is herein referred to as a "reaction step". **Reaction steps involve the** delivery of heat to the ceramic of an amount sufficient to activate solid-state diffusion mechanisms and crystalline ordering in the ceramic, which may comprise thermal heat treatments wherein the ceramic is exposed to an elevated temperature, or radiation treatments wherein heat is delivered to the ceramic through the absorption of electromagnetic radiation. Heat must be delivered to the ceramic in an amount equivalent to the amount of heat contained within the ceramic at a crystallization temperature.

Crystallizati n temperatur s f r